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Modification of σ-framework of [60]fullerene for bulk-heterojunction solar cells

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Modification of the σ-framework of [60]fullerene have been shown to be a new avenue toward n-type materials for bulk-heterojunction solar cells. This approach allowed distinct control of the LUMO level of the C₆₀ σ-system and resulted in a clear improvement of an open-circuit voltage.

π-Conjugated semiconductor materials have occupied a dominant position in organic thin-film photovoltaic devices, so called bulk-heterojunction (BHJ) solar cells. The core of the device is a single active layer which typically consists of a blend of electron-donating polymer, such as poly(3-hexylthiophene) (P3HT), and electron-accepting molecule, such as (6,6)-phenyl C₆₁-butryl acid methyl ester (PCBM). In the light of easy fabrication through solution process, flexibility, and large area application, the BHJ solar cell will be a potential alternative to conventional silicon-based solar cell, if the low power conversion efficiency (PCE) is overcome. During the last few years the PCEs have been rapidly improved largely owing to development of a wide variety of donor copolymers made of electron-rich and electron-poor building blocks with enhanced absorptions in the visible area.

It is well known that electronic properties of the donor polymers should be controlled to match those of the acceptors. For instance, the energy level of the lowest unoccupied molecular orbital (LUMO) of the donor is required to be higher than that of the acceptor by 0.3–0.5 eV to overwhelm the binding energy of excitons. Under the circumstances of the rapidly extended repertoire of the low band gap polymers, establishment of new methodology capable of tuning the electronic properties of the [60]fullerene is of increasing significance for creating rational acceptor/donor pair. However, most studies on the acceptors have so far been focused on the structural modification of the benchmark acceptor, PCBM, toward raising its LUMO energy level by (i) installation of electron-donating group(s) on its phenyl ring, (ii) saturation of one more C=C double bond on the fullerene cage to give almost inseparable mixture of regioisomers, and (iii) encapsulation of a trimetallic nitride cluster inside C₆₀ cage to give the endohedral PC₈bxBM analogs. As another approaches, 1,4-di(organo)C₆₀ derivatives and indene-C₆₀ bisadducts were recently reported.

During our studies on organic synthesis of endohedral fullerenes encapsulating small gaseous entities, so called molecular surgery, we have established techniques to modify the σ-framework of fullerenes to create a wide opening. The unique features of the skeletally-modified fullerenes (SMFs) lie in the retention of the 60r- or 70r-conjugated systems as well as appearance of rich chemical reactivity at the opening. Actually, as we reported recently, the opening of SMF derivative 1 could be effectively transformed to that of 2 and 3. These SMF derivatives have excellent solution processability due to two n-octyl chains.

<table>
<thead>
<tr>
<th>Compound</th>
<th>( E_{\text{red}} ) (V)</th>
<th>( E_{\text{red}} ) (V)</th>
<th>LUMO (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>C₆₀</td>
<td>–1.09</td>
<td>–1.49</td>
<td>–3.23</td>
</tr>
<tr>
<td>1</td>
<td>–1.00</td>
<td>–1.40</td>
<td>–3.03</td>
</tr>
<tr>
<td>2</td>
<td>–1.12</td>
<td>–1.52</td>
<td>–3.18</td>
</tr>
<tr>
<td>3</td>
<td>–1.23</td>
<td>–1.62</td>
<td>–3.00</td>
</tr>
<tr>
<td>PCBM</td>
<td>–1.17</td>
<td>–1.57</td>
<td>–3.04</td>
</tr>
</tbody>
</table>

Values for 0.5\( E_{\text{pa}} \) vs Fe/Ce²⁺ in 1.2-Cl₆C₆H₆ with 0.1 M Bu₄NBF₄ as supporting electrolyte; Pt wire as counter electrode and glassy carbon as working electrode; scan rate of 20 mV s⁻¹. Calculated at the B3LYP/6-31G* level of theory with replacement of the n-octyl groups to methyl groups. 

Electrochemical reduction potentials of SMFs 1–3, C₆₀, and PCBM investigated by cyclic voltammetry (CV) are summarized in Table 1 together with calculated LUMO energy levels. All SMFs 1–3 exhibited pseudo-reversible first to third reduction waves in the same manner as those for C₆₀ and PCBM. It is worth noting that the first reduction potentials \( E_{\text{red}} \) of SMFs 2 and 3 markedly shifted to negative upon the simple modifications from 1, that is, the sulfur insertion caused the negative shift by \( \Delta E_{\text{red}} \) = 120 mV and the functionalization of the carbonyl group resulted in the further negative shift by \( \Delta E_{\text{red}} \) = 110 mV, as supported by the results of DFT calculations. Thus, the present approach...
provides useful way to control the LUMO energy level of $C_{60}$ without causing significant loss of the native $\pi$-conjugation. Since an open-circuit voltage ($V_{oc}$) has an association with the energy difference between acceptor’s LUMO and donor’s HOMO, the higher LUMO energy level of 3 than that of PCBM should contribute to improve the $V_{oc}$ of the device when 3 is combined with a donor polymer with an adequately high LUMO level. On the other hand, UV-vis absorption spectra showed slightly enhanced absorption bands in a range of 300–500 nm for 1–3 with reference to PCBM (Fig. 1).

![Fig. 1 UV-vis absorption spectra of 1–3 and PCBM in cyclohexane.](image)

In order to observe the effects of controlled LUMO levels of SMFs on the open-circuit voltage, BHJ solar cells were fabricated using 1–3 as the acceptor with a combination of the representative donor polymer, 3HT, by basically following the procedure established for PCBM:3HT-based device. The devices with a layered structure of glass/ITO/PEDOT:PSS:SMF:3HT/TiO$_2$/Al were prepared as follows. The chlorobenzene solutions containing an SMF derivative and 3HT at weight ratio of 1:1.6 were spin-coated onto an indium tin oxide (ITO)/glass substrate covered with PEDOT:PSS layer under argon, and the resulting films were annealed at 150 °C for 6 min to induce phase separation. Then, TiO$_2$ layer was coated on the active layers in air and subsequently aluminum electrode was thermally deposited under vacuum. The optimum thickness of the BHJ films was approximately 80 nm. The surface morphology of the active layers of 1:3HT, 2:3HT, 3:3HT, and PCBM:3HT as a standard reference were observed by the use of atomic force microscopy (AFM) (Fig 2). All films using 1–3 showed fine features similar to that using PCBM. The root mean square (rms) roughness was 1.0 nm for 1:3HT, 0.9 nm for 2:3HT, 1.1 nm for 3:3HT, and 1.0 nm for PCBM:3HT, respectively, indicating that the domain size of all blend films was almost identical regardless of the skeleton-modifications of $C_{60}$ and the introduction of the $n$-octyl chains.

![Fig. 2 Tapping mode AFM images (10 $\mu$m × 10 $\mu$m) of blend films composed of (a) 1:3HT, (b) 2:3HT, (c) 3:3HT, and (d) PCBM:3HT measured after annealing.](image)

![Fig. 3 Current density–voltage ($J$–$V$) characteristics of BHJ solar cells based on the active layers of 1–3:3HT and PCBM:3HT under AM 1.5G illumination from a calibrated solar simulator.](image)

![Table 2 Characteristics of bulk-heterojunction solar cells$^a$](table)

<table>
<thead>
<tr>
<th>active layer</th>
<th>$V_{oc}$ (V)</th>
<th>$J_{sc}$ (mA cm$^{-2}$)</th>
<th>FF</th>
<th>$\eta$ (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1:3HT</td>
<td>0.49</td>
<td>5.20</td>
<td>0.53</td>
<td>1.35</td>
</tr>
<tr>
<td>2:3HT</td>
<td>0.62</td>
<td>6.49</td>
<td>0.62</td>
<td>2.49</td>
</tr>
<tr>
<td>3:3HT</td>
<td>0.74</td>
<td>6.57</td>
<td>0.64</td>
<td>3.11</td>
</tr>
<tr>
<td>PCBM:3HT</td>
<td>0.60</td>
<td>7.76</td>
<td>0.67</td>
<td>3.12</td>
</tr>
</tbody>
</table>

$^a$ Open-circuit voltage ($V_{oc}$), short-circuit current density ($J_{sc}$), fill factor (FF), and PCE ($\eta$) with 1–3 and PCBM as the acceptor materials and P3HT as the donor material. The active area of the device is 5.2 mm$^2$.

The typical current density–voltage curves for the BHJ solar cells under AM 1.5G conditions of 100 mW cm$^{-2}$ are shown in Fig. 3 and the device performances are summarized in Table 2. Actually, as expected, 1:3HT-based device marked a low $V_{oc}$ value (0.49 V), reflecting the relatively low-lying LUMO energy level. This value was clearly improved to 0.62 V for 2:3HT-based device and further to 0.74 V for 3:3HT-based device. As shown in Fig. 4, the linear regression indicated the clear correlation ($r^2 = 1.0$) between the LUMO energy levels of the SMF derivatives and the $V_{oc}$ values, although the point for PCBM:3HT appears to deviate downward. It is worth noting that the $V_{oc}$ of 3:3HT-based device was superior to that of PCBM:3HT device ($V_{oc}$ = 0.60 V) by $\Delta V_{oc} = 140$ mV. This $\Delta V_{oc}$ is much larger than the value achieved by the introduction of electron-donating groups on the phenyl ring of PCBM ($\Delta V_{oc}$ = 0.49 V).
These data demonstrated that the SMF derivatives are potential n-type materials with tunable LUMO levels for BHJ solar cells.

On the other hand, the short-circuit current densities ($J_\text{sc}$) of 2:P3HT and 3:P3HT-based devices ($J_\text{sc} = 6.49$ and $6.57$ mA cm$^{-2}$, respectively) slightly decreased with reference to that of PCBM:P3HT-based device ($J_\text{sc} = 7.76$ mA cm$^{-2}$), while the fill-factors (FF) were almost identical. One possible reason would be that the presence of two n-octyl chains prevented the effective intermolecular $\pi$-$\pi$ interaction between C$_{60}$ cages and hence decreased the charge mobility.$^{37}$ As a result, in the combination with P3HT, the device using 3 provided the best PCE ($\eta_e = 3.11\%$), which is comparable to that of the benchmark PCBM:P3HT-based device ($\eta_e = 3.12\%$).$^{18}$ The particularly low values of $J_\text{sc}$ (5.20 mA cm$^{-2}$) and FF (0.53) obtained for 1:P3HT-based device probably resulted from the increased charge recombination in BHJ film. Actually, the shape of the LUMO was relatively localized at the opening (see the Supporting Information). The almost completely delocalized LUMOs of 2 and 3 as well as PCBM are considered to contribute to their improved $J_\text{sc}$ and FF.

In summary, we have demonstrated that the structural manipulation of the C$_{60}$ skeleton is a promising approach for the creation of acceptor materials for BHJ solar cells. This approach can be used to effectively control the electronic properties of the C$_{60}$ moiety with the original 60r-conjugation being largely retained to rationally match the LUMO level to that of the donor materials. Actually, by combining the SMF derivatives with typical donor polymer, P3HT, we obtained the higher $V_{\text{oc}}$ value of 0.74 V than that of PCBM:P3HT-based device by $\Delta V_{\text{oc}} = 140$ mV. In order to improve the performance of the BHJ solar cells, it is also indispensable to enhance the carrier mobility. We are currently studying the structural optimization of the substituents toward improvement of the morphology in the BHJ films.

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Notes and references

18. Probably because of batch-to-batch variation in the quality of P3HT, the PCE of the device using PCBM decreased to 3.1% compared with 4% as reported earlier, see: ref. 15.